

TPN3021

Application Specific Discretes
A.S.D.TM

TRIPOLAR OVERVOLTAGE PROTEC-TION FOR NETWORK INTERFACES

FEATURES

- TRIPLE CROWBAR PROTECTION
- PEAK PULSE CURRENT : IPP = 30 A, 10/1000 µs
- VERY LOW CAPACITANCE: C = 30 pF
- PROTECTS HIGH-SPEED LINE DRIVERS / RECEIVERS



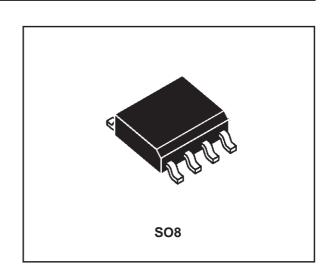
Dedicated to dataline protection, this device provides a triple protection function. It ensures the same protection capability with the same breakdown voltage both in common mode and in differential mode.

With a stand-off voltage of 28V and a very low capacitance, this device is able to protect high-speed interfaces such as T1/E1 interface.

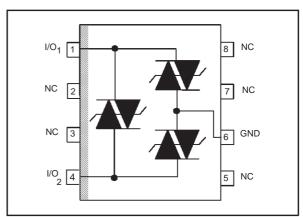
COMPLIES WITH THE FOLLOWING STANDARDS:

- IEC801-2 15kV (air discharge)- IEC801-4 40A (repetitive 2.5kHz)

- IEC801-5 1.2/50μs 4kV 8/20μs 100A



SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS $(T_{amb} = 25 \, ^{\circ}C)$

Symbol	Parameter	Value	Unit	
I _{pp}	Peak pulse current	10/1000 μs 8/20 μs	30 150	A A
T _{stg} Tj	Storage temperature range Maximum junction temperature	- 40 to + 150 150	°C °C	
TL	Maximum lead temperature for soldering duri	260	°C	

THERMAL RESISTANCE

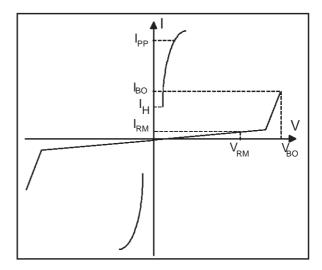
Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	170	°C/W

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ELECTRICAL CHARACTERISTICS (T_{amb}=25°C)

Symbol	Parameter		
V _{RM}	Stand-off voltage		
Vво	Breakovervoltage		
V _{BR}	Breakdown voltage		
lΗ	Holding current		
I _{BO}	Breakovercurrent		
I _{RM}	Leakage current at V _{RM}		
I _{PP}	Peak pulse current		
С	Capacitance		
αΤ	Temperature coefficient		



Туре	I _{RM} @ V _{RM} max.		V _{во} @ во max.		I _H min.	typ.	max.	αT typ.
	note 1				note 2	not	te 3	note 4
	μΑ	V	V	mA	mA	pF	pF	10 ⁻⁴ /°C
TPN3021	4	28	38	100	30	25	30	8

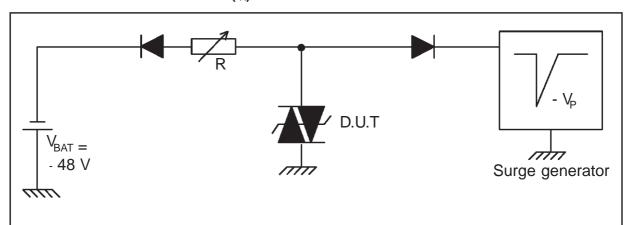
Note 1: Between any I/Opin and Ground or between I/O1 and I/O2.

Note 2: See the functional holding current (IH) test circuit.

Note 3: Between any I/Opin and GND or between I/O1 and I/O2 at 0V bias, VRMS = 30 mV, F = 1 MHz.

Note 4: $\Delta V_{BO} = \alpha T \times (T_{amb} - 25) \times V_{BO}(25^{\circ}C)$.

FUNCTIONAL HOLDING CURRENT (IH) TEST CIRCUIT: GO-NO GO TEST



This is a GO-NO GO test which allows to confirm the holding current (IH) level in a functional test circuit.

TEST PROCEDURE:

- Adjust the current level at the I_H value by short circuiting the D.U.T.
- Fire the D.U.T. with a surge current : $I_{pp} = 10A$, $10/1000 \,\mu s$.
- The D.U.T. will come back to the off-state within a duration of 50 ms max.

APPLICATION CIRCUIT: T1/E1 Interface Protection

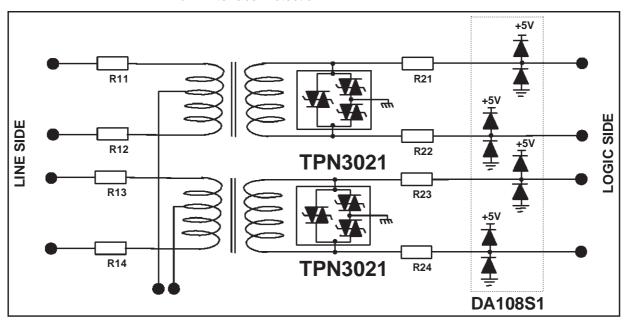
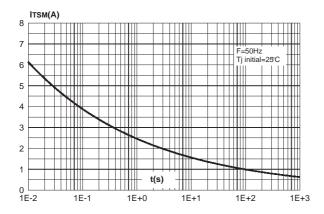
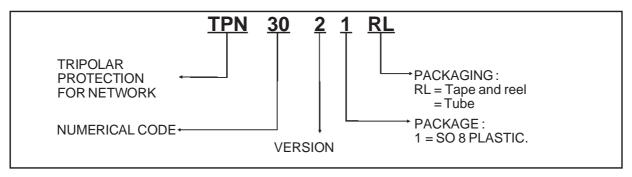


Fig. 1: Surge peak current versus overload duration.



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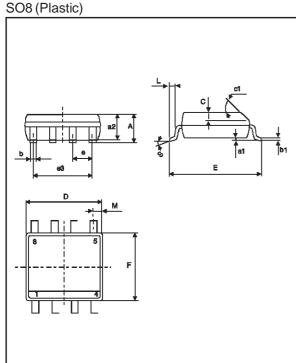
ORDER CODE



Marking

Туре	Marking		
TPN3021	TPN302		

PACKAGE MECHANICAL DATA



	DIMENSIONS						
REF.	Millimetres			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С		0.50			0.020		
c1			45°	(typ)			
D	4.8		5.0	0.189		0.197	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.15		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max)						

Packaging = Products supplied in antistatic tubes or tape and reel.

Weight = 0.08 g

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